Chapter 1

Detectors for Particle Physics

1.1 Recap: interaction of particles with matter

The way we identify particles is through their interaction with matter. So, we can detect:

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- Charged particles based on ionization, breamsstrahlung, Cherenkov.
- γ -rays based on photo/compton effect, pair production.
- Neutrons based on strong interaction.
- Neutrinos based on weak interaction.

We will give only a phenomenological treatment since the goal is to be able to understand the implications for detector design.

1.1.1 Ionization

The equation that describe this interaction is the **Bethe-Bloch Equation**

$$-\left\langle \frac{\mathrm{d}E}{\mathrm{d}x} \right\rangle = K\rho \frac{Z}{A} \frac{z^2}{\beta^2} \left[\frac{1}{2} \log \frac{2m_e c^2 \beta^2 \gamma^2 T_{\mathrm{max}}}{I^2} - \beta^2 - \frac{\delta(\beta \gamma)}{2} - \frac{C}{z} \right] \tag{1.1}$$

1.1.2 Breamsstrahlung

$$-\left\langle \frac{\mathrm{d}E}{\mathrm{d}x}\right\rangle = \frac{E}{X_0} \tag{1.2}$$

where X_0 is the radiation length in [g/cm²] and its expression (approximation) is:

$$X_0 = \frac{A}{4\alpha N_A Z^2 r_e^2 \log \frac{183}{Z_1^{\frac{1}{3}}}} \tag{1.3}$$

After the passage of one X_0 , electron has lost all but $(1/e)^{\text{th}}$ of its energy, namely 63%.

The critical energy E_C is the energy for which:

$$\left(\frac{\mathrm{d}E}{\mathrm{d}x}\right)_{\mathrm{ion}} = \left(\frac{\mathrm{d}E}{\mathrm{d}x}\right)_{\mathrm{rad}} \tag{1.4}$$

An approximation is:

$$E_C \approx \frac{600 \text{ MeV}}{Z} \tag{1.5}$$

1.1.3 Total energy loss for electrons

Ionization losses decrease logarithmically with E and increase linearly with Z. Bremsstrahlung increases approximately linearly with E and is the dominant process at high energies.

1.1.4 Interaction of photon with the matter

Photon lose energy by:

- Photoelectric effect on atoms at low energy.
- Compton effect important at intermediate range.
- Pair production.

In our case pair production is dominant:

$$\sigma_{\text{pair}} = \frac{7}{9} \frac{N_A}{A} \frac{1}{X_0} \tag{1.6}$$

1.2 Detectors: gaseous, scintillators and

1.2.1 Ionization in gas detectors

Primary ionization:

$$Particle + X \longrightarrow X^{+} + e^{-} + Particle \tag{1.7}$$

Secondary ionization:

$$X + e^- \longrightarrow X^+ + e^- + e^- \tag{1.8}$$

The relevant parameters to evaluate the number of particles produced are the ionization energy E_i , the average energy/ion pair W_i and the average number of ion pairs (per cm) n_T . In particular:

$$\langle n_T \rangle = \frac{L \left\langle \frac{\mathrm{d}E}{\mathrm{d}x} \right\rangle}{W_i} \tag{1.9}$$

with L the thickness of the material. Typical values for E_i are

Concerning the diffusion, it is significantly modified by the presence of a magnetic field, with transverse and longitudinal orientation depending on it. By measuring the bending of the particle, we are able to infer the momentum of the particle itself. The electric field influences only the longitudinal diffusion and not the transverse diffusion.

The electrons can undergo to a multiplication process called townsend avalanche. Given the number of electrons at the position x, $n(x) = n_0 e^{\alpha x}$, we have the gain:

$$G = \frac{n(x)}{n_0} = e^{\alpha x} \tag{1.10}$$

where α can depend on x.

There are four regions of work:

• Geiger-Muller coun

1.2.2 Multiwire proportional chambers

Signal generations: electron drift to closest wire, gas amplification near wire that creates avalanche

1.2.3 Drift chambers

In this case we can have two dimensional informations through time measurements, namely drift time measurement. It starts by an external detector such as a scintillator counter. Electrons drift to the anode in the field created by anode and cathode. The electron arrival at the anode stops in the time measurement.

$$x = \int_0^{t_D} v_D dt \tag{1.11}$$

We build the detector with a known drift velocity. We can introduce field wires

1.2.4 Semiconductor detectors

Semiconductor detectors have the following characteristics:

- High density (respect to gas detectors), so large energy loss in a short distance
- A small diffusion effect, so position resolution of less than 10 μm
- Low ionization energy, so it is easier to produce particles.

The materials employed for their construction are:

- Germanium, which needs to be operated at a very low temperature (77 K) due to small band gap.
- Silicon, which can operate at room temperature.
- Diamond, resistent to very hard radiations, low signal and high cost.

Silicon detectors are based on a p-n junction with reverse bias applied to enlarge the depletion region. The potential barrier becomes higher so that the diffusion across the junction is suppressed and the current across the junction is very small ("leakage current").

Such a detector can be built in strips. By segmenting the implant we can reconstruct the position of hte transversing particle in one dimension. We have a higher field close to the collecting electrodes where most of the signal is induced. Strips can be read with dedicated electronics to minimize the noise. To have 2-dimensional measurements, double sided silicon detector are used. A type of silicon detector still in development is the pixel detector (for 3-dimensional measurements).

Noise contributions can be leakage current and electronics readout.

Position resolution is the spread of the reconstructed position minus the true position. For example:

$$\sigma = \frac{\text{pitch}}{\sqrt{12}} \qquad \text{One strip cluster} \tag{1.12}$$

$$\sigma = \frac{\text{pitch}}{1.5 \frac{S}{N}}$$
 Two strip cluster (1.13)

1.3 Track reconstruction

Track reconstruction is used to determine momentum of charged particles by measuring the bending of a particle trajectory in a magnetic field